S.V.UNIVERSITY, TIRUPATI

B.Sc- ELECTRONICS-SYLLABUS

SEMESTER: II – W.E.F. 2015-16

PAPER 2 -ELECTRONIC DEVICES&CIRCUITS

(60hrs)

UNIT I(12hrs)

**JUNCTION DIODES** 

PN junction diode – P-N junction theory-depletion region, barrier potential, working in forward& reverse bias condition, Junction capacitance, Diode current equation (no derivation), Effect of temperature on reverse saturation current, V-I Characteristics, Zener and Avalanche Break down, Zener diode - V-I characteristics regulated power supply using Zener diode, Varactor Diode, Tunnel Diode – Principle, Working& Applications.

UNIT II(16hrs)

**BIPOLAR JUNCTION TRANSISTORS (BJT)** 

PNP and NPN transistors, current components in BJT, BJT static characteristics (Input and Output), Early effect, CB.CE,CC Configurations (Cut-off, Active and saturation regions), h-parameters, h-parameter equivalent circuit. Determination of h-parameters from the characteristics, Concept of amplification-voltage and current amplifier. Biasing and load line analysis, Fixed bias, voltage divider bias arrangements, The C.E amplifier-analysis and parameters, Transistor as a switch.

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UNIT III(12hrs)

FIELD EFFECT TRANSISTORS&UJT

FET - Construction - Working - Drain&Transfer characteristics - Parameters of FET - FET as an amplifier-MOSFET-Enhancement MOSFET - Depletion MOSFET - Construction& Working-Drain characteristics of MOSFET - Comparison of FET&BJT and JFET&MOSFET.

UJT Construction-working, V-I Characteristics

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#### UNIT IV (8hrs)

#### PHOTO ELECTRIC DEVICES

Structure and operation, characterstics, spectral response and applications of LDR, Photo Voltaic cell, Photo diode, Photo transistor, LED and LCD

#### UNIT V (12hrs)

#### POWER SUPPLIES

Rectifiers – Half wave, full wave and bridge rectifiers – Efficiency – Ripple factor – Regulation Types of filter- Choke input (Inductor) filter – shunt capacitor filter –L-Section and  $\pi$  section filters — Voltage regulators- Transistor Series and shunt regulators – Block diagram of regulated power supply, Three terminal fixed voltage I.C regulators (78XX and 79XX) - Principle and working of switch mode power supplies (SMPS).

#### **TEXT BOOKS**

- 1. Electronic Devices and Circuits David A.Bell, Fifth edition, Oxford university press
- 2. A.P Malvino, "Principles of Electronics", TMH, 7th edition
- 3.D.Roy Choudary, Linear Integrated Circuits, New Age International Pvt. Ltd.
- 4. T.F. Bogart, Beasley, "Electronic Devices and circuits", Pearson Education, 6th Edition
- N.N. Bhargava, D.C Kulshreshta, and S.C Gupta, "Basic Electronics and Linear Circuits" TMH,
- 6. T.L.Floyd, "Electronic Devices and circuits", PHI, fifth edition
- 7. V.K. Mehta, "Principle of Electronics", S CHAND Co. New edition
- 8. Godse A.P., Bakshi U.A (1st edition), Electronics Devices, Technical Publications Pune.

#### REFERENCE BOOKS

- 1. Sedha R.S., A TextBook of Applied Electronics, S. Chand & Company Ltd.
- 2. Jacob Millman and Christos C. Halkias (2008) Integrated Electronics, Tata Mcgraw-Hill
- 3. Robert L. Boylestad, Louis Nashelsky (10th edition), Electron Devices and Circuit Theory, Dorling Kindersley(India Pvt. Ltd.)

#### **ELECTRONICS LAB – 2**

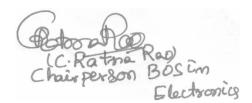
# (ELECTRONIC DEVICES&CIRCUITS LAB)

#### (Any <u>six</u> experiments should be done)

- 1. V-I Characteristics of Junction Diode.
- 2. V-I Characteristics of Zener Diode.
- 3. Regulated Power Supply using Zener Diode.
- 4. IC Regulated Power Supply
- 5. BJT input and output Characteristics (CE Configuration) and determination of h- parameters.
- 6. Characteristics of UJT.
- 7. Characteristics of JFET
- 8. LDR characteritics
- 9. Characteristics of L and  $\Pi$  section filters with fullwave rectifier

#### LAB MANUAL

- 1. Zbar, Malvino and Miller, Basic Electronics, A Text Lab Manual, Tata McGraw Hill.
- 2. Sugaraj Samuel R., Horsley Solomon, B.E.S. Practicals.



#### **MODEL PAPER**

# B.Sc (Three year ) Degree Examinations. SEMISTER-II ELECTRONICS

### Paper-II ELECTRONIC DEVICES AND CIRCUITS

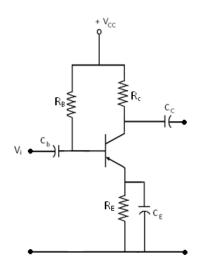
Time: 3 Hrs MaxMarks:75

#### **PART-A**

Answer any FIVE Questions

5x5 = 25 Marks.

- 1. Explain Zener and Avalanche break down.
- 2. Explain Junction capacitance of a P-N Junction diode.
- 3. Define Hybrid parameters of a Transistor.
- 4. Find the operating point for the bias circuit shown in the fig. provided Vcc = 9V ,  $R_B$  = 50K $\Omega$ ,  $R_c$  = 250 $\Omega$ ,  $R_E$  =500 $\Omega$  and  $\alpha$ = 80.



- 5. What are the advantages of FET over BJT.
- 6. Write the operation of photo voltaic cell.
- 7. Draw the circuit diagram of  $\pi$  section filter and discuss its working.
- 8. Discuss the working of Transistor series Voltage regulator.

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#### **PART-B**

#### **Answer ALL Questions**

10X5 = 50 marks.

9(a) . Explain forward and reverse bias effects in the V-I Curves of a P-N Junction diode.

(or)

- (b) . Describe the construction and working of a Tunnel diode. Draw its V-I Characteristics and explain.
- 10(a).Draw the input and Output Characteristics of a CE mode of a Transistor . Define Cut-off , Active and saturation region in the characteristics.

(or)

- (b).Describe about fixed bias and voltage divider bias of a Transistor . Give their merits and demerits.
- 11(a). Explain the Construction, working of JFET.

(or)

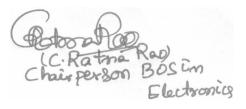
- (b). What is a UJT? Describe the Volt-Ampere Characteristics of a UJT.
- 12(a). Explain operation of photoconductive cell and discuss its spectral response.

(or)

- (b). Explain Construction and working of LED and write its merits and uses.
- 13(a).A full wave rectifier uses a centre tapped Transformer . The a.c. Voltage from its centre tap to either end is 10 Sin 314t. The load resistance of the circuit is  $40\Omega$  and Diode resistance  $10\Omega$ . Find  $I_{dc},I_{rms}$ , ripple factor and rectifier efficiency.

(or)

(b).Explain the Principle and working of switch mode power supply (SMPS) with the help of block diagram.



# **B.Sc- ELECTRONICS PRACTICALS**

## SCHEME OF VALUATION FOR ALL SEMESTERS

1.Principle/Statement	2marks
2.Circuit diagram with component la	abelling5marks
3. Tabular form/Formula/Model graph	n6marks(3+2+1)
4.Observations	12marks
5.Calculations/Graph/Result	10marks(5+3+2)
6.Viva	5marks
7.Record	10marks
	TOTAL= 50marks

